



#### 40V PNP MEDIUM POWER HIGH GAIN TRANSISTOR

#### **Features**

- $BV_{CEO} > -40V$
- Ic = -3A High Continuous Collector Current
- Iсм = -6A Peak Pulse Current
- High Gain Device >200 @-1A
- $R_{CE(SAT)} = 83m\Omega$  Typical
- Low Saturation Voltage
- Lead-Free Finish; RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.34 grams (Approximate)

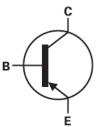
#### **Application**

- **DC-DC Converters**
- **MOSFET Gate Drivers**
- **Charging Circuits**
- **Power Switches**
- Siren Drivers

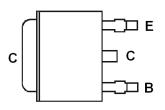
# **TO252 (DPAK)**



Top View



**Device Schematic** 



Pin Out Configuration Top view

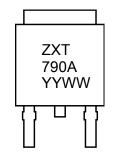
#### **Ordering Information** (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXT790AKTC	ZXT790A	13	16	2,500

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



ZXT790A = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week Code (01 to 53)



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	BV <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	BV <sub>CEO</sub>	-40	V
Emitter-Base Voltage	BV <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-3	Α
Base Current	I <sub>B</sub>	-0.5	A
Peak Pulse Collector Current	I <sub>CM</sub>	-6	А

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		2.1		
Power Dissipation	(Note 6)	$P_{D}$	3.0	W	
	(Note 7)		3.9		
	(Note 5)		59	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	41		
	(Note 7)		32		
Operating and Storage Temperature Range	$T_{J,T_{STG}}$	-55 to +150	°C		

# ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3B
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

<sup>5.</sup> For a device mounted with the exposed collector pad on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

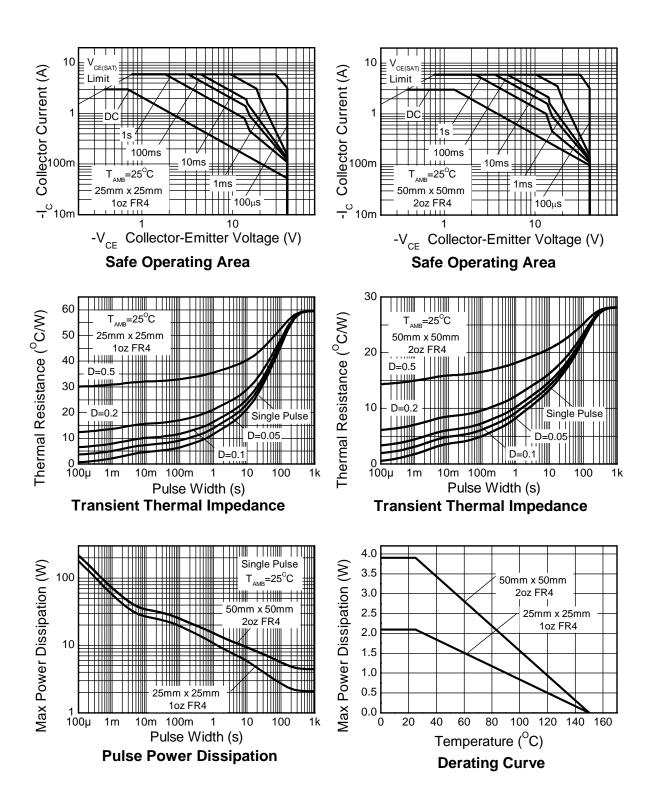
6. Same as note (5), except mounted on 50mm x 50mm 1oz copper.

7. Same as note (5), except mounted on 50mm x 50mm 2oz copper.

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



#### **Thermal Characteristics and Derating Information**





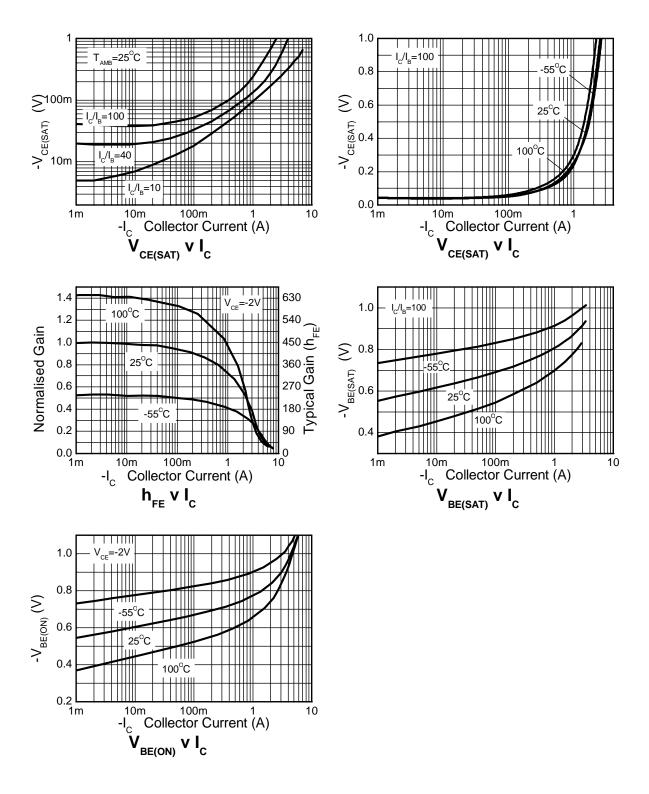
# **Electrical Character**istics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	-50	-70	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-40	-60	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.3	_	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	ı	<1	-20	nA	V <sub>CB</sub> = -30V
Emitter Cutoff Current	I <sub>EBO</sub>	_	<1	-20	nA	V <sub>EB</sub> = -6V
Emitter Cutoff Current	I <sub>CES</sub>	-	<1	-20	nA	V <sub>CB</sub> = -30V
DC Current Transfer Static Ratio (Note 9)	h <sub>FE</sub>	300 250 200 150 80	450 390 350 280 170	800 — — — —	_	$\begin{split} & I_{C} = -10 \text{mA}, \ V_{CE} = -2 \text{V} \\ & I_{C} = -500 \text{mA}, \ V_{CE} = -2 \text{V} \\ & I_{C} = -1 \text{A}, \ V_{CE} = -2 \text{V} \\ & I_{C} = -2 \text{A}, \ V_{CE} = -2 \text{V} \\ & I_{C} = -3 \text{A}, \ V_{CE} = -2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(SAT)</sub>	1	-110 -220 -260 -250	-170 -350 -450 -450	mV	$I_C = -0.5A$ , $I_B = -5mA$ $I_C = -1A$ , $I_B = -10mA$ $I_C = -2A$ , $I_B = -50mA$ $I_C = -3A$ , $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(SAT)}$	_	-1.05	-1.15	V	$I_C = -3A$ , $I_B = -300mA$
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(ON)</sub>	-	-0.90	-1.0	V	$I_C = -3A$ , $V_{CE} = -2V$
Transitional Frequency	f⊤	100	_	_	MHz	$I_C = -50$ mA, $V_{CE} = -5V$ f = 50MHz
Output Capacitance	Сово	_	24	_	pF	$V_{CB} = -10V, f = 1MHz,$
Switching Times	t <sub>ON</sub> toff	_	35 600	_	ns	$I_{C}$ = -500mA, $V_{CC}$ = -10V, $I_{B1}$ = -50mA $I_{B2}$ = 50mA

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤2%.



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

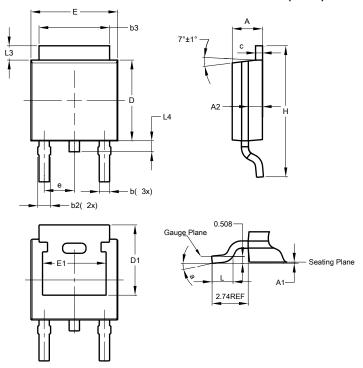




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **TO252 (DPAK)**

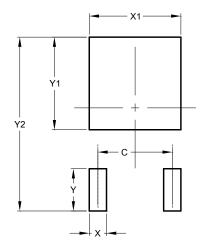


TO252 (DPAK)				
Dim	Min	Max	Тур	
Α	2.19	2.39	2.29	
A1	0.00	0.13	0.08	
A2	0.97	1.17	1.07	
b	0.64	0.88	0.783	
b2	0.76	1.14	0.95	
b3	5.21	5.46	5.33	
C	0.45	0.58	0.531	
D	6.00	6.20	6.10	
D1	5.21	_	_	
е	_	_	2.286	
Е	6.45	6.70	6.58	
E1	4.32	_	-	
Н	9.40	10.41	9.91	
L	1.40	1.78	1.59	
L3	0.88	1.27	1.08	
L4	0.64	1.02	0.83	
а	0°	10°	_	
All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
Y2	10 700		



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